



5.0 A Throttle Control H-Bridge

The 33932 is a monolithic H-Bridge Power IC in a robust thermally enhanced package. The 33932 has two independent monolithic H-Bridge Power ICs in the same package. They are designed primarily for automotive electronic throttle control, but are applicable to any low-voltage DC servo motor control application within the current and voltage limits stated in this specification.

Each H-bridge in the 33932 is able to control inductive loads with currents up to 5.0 A peak. RMS current capability is subject to the degree of heatsinking provided to the device package. Internal peak-current limiting (regulation) is activated at load currents above 6.5 A ± 1.5 A. Output loads can be pulse width modulated (PWM-ed) at frequencies up to 11 kHz. A load current feedback feature provides a proportional (0.24% of the load current) current output suitable for monitoring by a microcontroller's A/D input. A Status Flag output reports under-voltage, over-current, and over-temperature fault conditions.

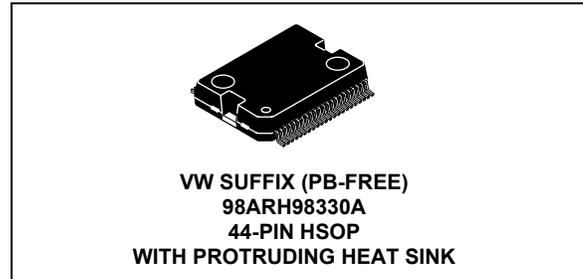
Two independent inputs provide polarity control of two half-bridge totem-pole outputs. Two independent disable inputs are provided to force the H-bridge outputs to tri-state (high-impedance off-state).

Features

- 8.0 to 28 V continuous operation (transient operation from 5.0 to 40 V)
- 235 m Ω maximum $R_{DS(ON)}$ @ 150°C (each H-Bridge MOSFET)
- 3.0 V and 5.0 V TTL / CMOS logic compatible inputs
- Over-current limiting (regulation) via internal constant-off-time PWM
- Output short-circuit protection (short to VPWR or GND)
- Temperature-dependant current-limit threshold reduction
- All inputs have an internal source/sink to define the default (floating input) states
- Sleep Mode with current draw < 50 μ A (each half with inputs floating or set to match default logic states)

33932

THROTTLE CONTROL H-BRIDGE



ORDERING INFORMATION		
Device	Temperature Range (T _A)	Package
MC33932VW/R2	-40°C to 125°C	44 HSOP

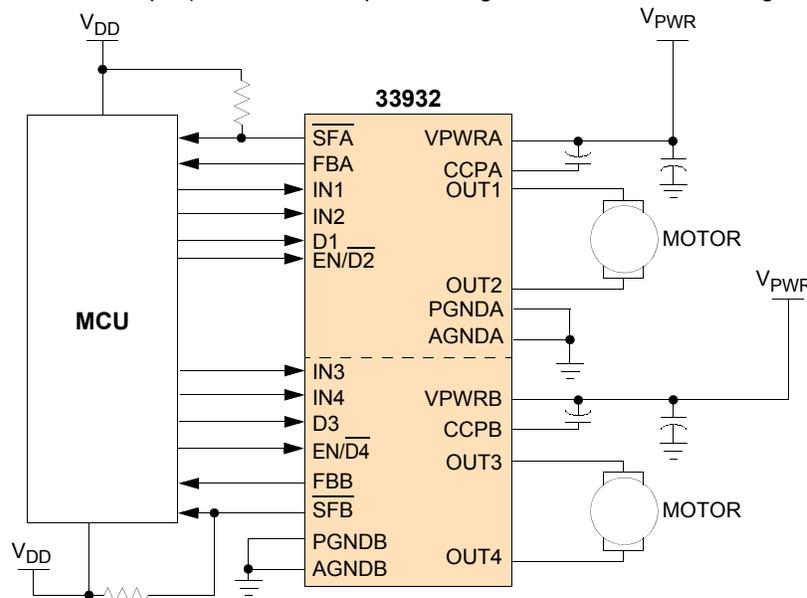


Figure 1. MC33932 Simplified Application Diagram

* This document contains certain information on a new product. Specifications and information herein are subject to change without notice.

INTERNAL BLOCK DIAGRAM

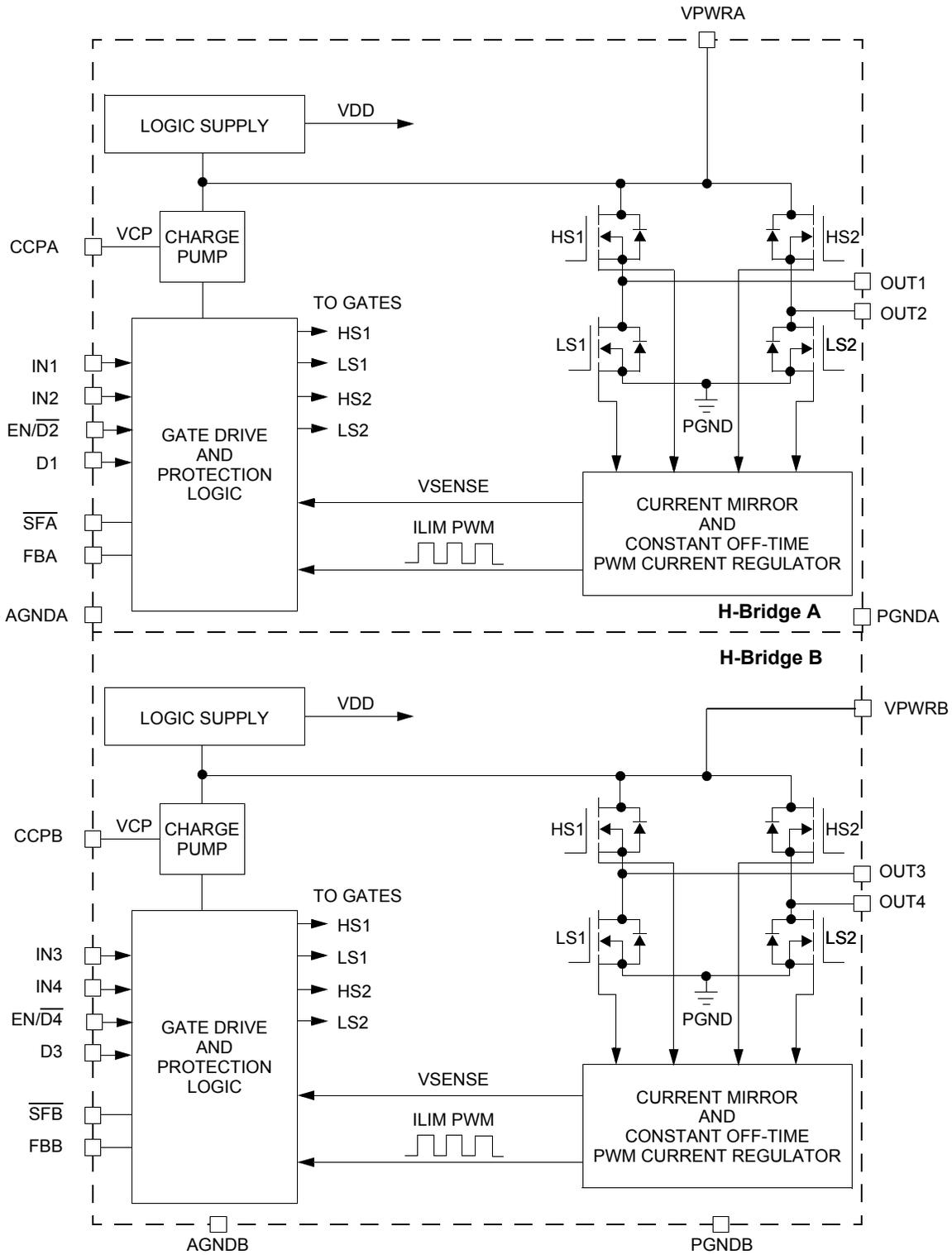


Figure 2. 33932 Simplified Internal Block Diagram

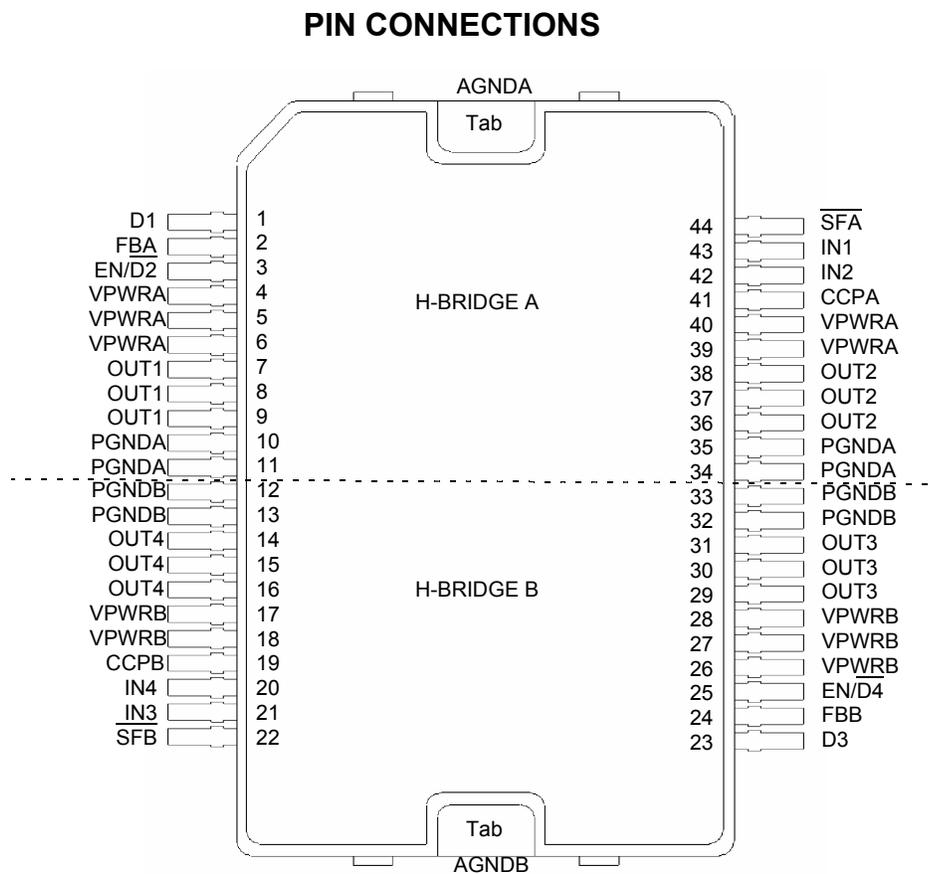


Figure 3. 33932 Pin Connections

Table 1. 33932 Pin Definitions

A functional description of each pin can be found in the Functional Description section beginning on page 11 .				
Pin	Pin Name	Pin Function	Formal Name	Definition
1	D1	Logic Input	Disable Input 1 (Active High)	When D1 is logic HIGH, both OUT1 and OUT2 are tri-stated. Schmitt trigger input with ~80 μ A source so default condition = disabled.
2	FBA	Analog Output	Feedback	H-Bridge A load current feedback output provides ground referenced 0.24% of the high side output current. (Tie to GND through a resistor if not used.)
3	EN/ $\overline{D2}$	Logic Input	Enable Input	When EN/ $\overline{D2}$ is logic HIGH, H-Bridge A is operational. When EN/ $\overline{D2}$ is logic LOW, the H-Bridge A outputs are tri-stated and H-bridge A is placed in Sleep Mode. (logic input with ~80 μ A sink so default condition = Sleep Mode.)
4-6,39,40	VPWRA VPWRB	Power Input	Positive Power Supply	These pins must be connected together physically as close as possible and directly soldered down to a wide, thick, low resistance supply plane on the PCB.
7-9	OUT1	Power Output	H-Bridge Output 1	H-bridge A source of high side MOSFET1 and drain of low side MOSFET1.
10,11,34,35	PGNDA	Power Ground	Power Ground	High-current power ground pins must be connected together physically as close as possible and directly soldered down to a wide, thick, low resistance ground plane on the PCB.
12,13,32,33	PGNDB	Power Ground	Power Ground	High-current power ground pins must be connected together physically as close as possible and directly soldered down to a wide, thick, low resistance ground plane on the PCB.

Table 1. 33932 Pin Definitions (continued)

A functional description of each pin can be found in the Functional Description section beginning on page 11 .				
Pin	Pin Name	Pin Function	Formal Name	Definition
14-16	OUT4	Power Output	H-Bridge Output 4	H-bridge B Source of high side MOSFET2 and drain of low side MOSFET2.
17,18,26-28	VPWRB	Power Input	Positive Power Supply	These pins must be connected together physically as close as possible and directly soldered down to a wide, thick, low resistance supply plane on the PCB.
19	CCPB	Analog Output	Charge Pump Capacitor	External reservoir capacitor connection for H-bridge B internal charge pump; connected to VPWRB. Allowable values are 30 to 100 nF. Note: This capacitor is required for the proper performance of the device.
20	IN4	Logic Input	Input 4	Logic input control of OUT4.
21	IN3	Logic Input	Input 3	Logic input control of OUT3.
22	$\overline{\text{SFB}}$	Logic Output - Open Drain	Status Flag B (Active Low)	H-bridge B open drain active LOW Status Flag output (requires an external pull-up resistor to V_{DD} . Maximum permissible load current < 0.5 mA. Maximum V_{CEsat} < 0.4 V @ 0.3 mA. Maximum permissible pull-up voltage < 7.0 V.)
23	D3	Logic Input	Disable Input 3 (Active High)	When D3 is logic HIGH, both OUT3 and OUT4 are tri-stated. Schmitt trigger input with ~80 μA source so default condition = disabled.
24	FBB	Analog Output	Feedback B	H-bridge B load current feedback output provides ground referenced 0.24% of the high side output current. (Tie to GND through a resistor if not used.)
25	$\overline{\text{EN/D4}}$	Logic Input	Enable Input	When $\overline{\text{EN/D4}}$ is logic HIGH, H-bridge B is operational. When $\overline{\text{EN/D4}}$ is logic LOW, the H-bridge B outputs are tri-stated and H-bridge B is placed in Sleep Mode. (logic input with ~80 μA sink so default condition = Sleep Mode.)
29-31	OUT3	Power Output	H-Bridge Output 3	H-bridge B Source of high side MOSFET1 and drain of low side MOSFET1.
36-38	OUT2	Power Output	H-Bridge Output 2	H-Bridge A source of high side MOSFET2 and drain of low side MOSFET2.
41	CCPA	Analog Output	Charge Pump Capacitor	External reservoir capacitor connection for H-bridge A internal charge pump; connected to VPWRA. Allowable values are 30 to 100 nF. Note: This capacitor is required for the proper performance of the device.
42	IN2	Logic Input	Input 2	Logic input control of OUT2.
43	IN1	Logic Input	Input 1	Logic input control of OUT1; e.g., when IN1 is logic HIGH, OUT1 is set to VPWRA, and when IN1 is logic LOW, OUT1 is set to PGNDA. (Schmitt trigger Input with ~80 μA source so default condition = OUT1 HIGH.)
44	$\overline{\text{SFA}}$	Logic Output - Open Drain	Status Flag (Active Low)	H-Bridge A open drain active LOW Status Flag output (requires an external pull-up resistor to V_{DD} . Maximum permissible load current < 0.5 mA. Maximum V_{CEsat} < 0.4 V @ 0.3 mA. Maximum permissible pull-up voltage < 7.0 V.)
TAB	AGNDA AGNDB	Analog Ground	Analog Signal Ground	The low-current analog signal ground must be connected to PGND via low-impedance path (<<10 m Ω , 0 Hz to 20 kHz). Exposed TAB is also the main heatsinking path for the device.

ELECTRICAL CHARACTERISTICS

MAXIMUM RATINGS

Table 2. Maximum Ratings

All voltages are with respect to ground unless otherwise noted. Exceeding these ratings may cause a malfunction or permanent damage to the device. These parameters are not production tested.

Ratings	Symbol	Value	Unit
ELECTRICAL RATINGS			
Power Supply Voltage			V
Normal Operation (Steady-state)	$V_{PWR(SS)}$	-0.3 to 28	
Transient Overvoltage ⁽¹⁾	$V_{PWR(T)}$	-0.3 to 40	
Logic Input Voltage ⁽²⁾	V_{IN}	-0.3 to 7.0	V
\overline{SFA} , \overline{SFB} Output ⁽³⁾	$V_{\overline{SF}}$	-0.3 to 7.0	V
Continuous Output Current ⁽⁴⁾	$I_{OUT(CONT)}$	5.0	A
ESD Voltage ⁽⁵⁾			V
Human Body Model	V_{ESD1}	±2000	
Machine Model	V_{ESD2}	±200	
Charge Device Model			
Corner Pins (1,9,17,25)		±750	
All Other Pins		±500	
THERMAL RATINGS			
Storage Temperature	T_{STG}	-65 to 150	°C
Operating Temperature ⁽⁶⁾			°C
Ambient	T_A	-40 to 125	
Junction	T_J	-40 to 150	
Peak Package Reflow Temperature During Reflow ^{(7), (8)}	T_{PPRT}	Note 8	°C
Approximate Junction-to-Case Thermal Resistance ⁽⁹⁾	R_{THJC}	<1.0	°C/W

Notes

- Device will survive repetitive transient over-voltage conditions for durations not to exceed 500ms @ duty cycle not to exceed 10%. External protection is required to prevent device damage in case of a reverse battery condition.
- Exceeding the maximum input voltage on IN1, IN2, IN3, IN4, EN/D2, EN/D4, D1, or D3 may cause a malfunction or permanent damage to the device.
- Exceeding the pull-up resistor voltage on the open drain \overline{SFA} or \overline{SFB} pin may cause permanent damage to the device.
- Continuous output current capability is dependent on sufficient package heatsinking to keep junction temperature $\leq 150^\circ\text{C}$.
- ESD testing is performed in accordance with the Human Body Model ($C_{ZAP} = 100 \text{ pF}$, $R_{ZAP} = 1500 \Omega$), Machine Model ($C_{ZAP} = 200 \text{ pF}$, $R_{ZAP} = 0 \Omega$), and the Charge Device Model (CDM), Robotic ($C_{ZAP} = 4.0 \text{ pF}$).
- The limiting factor is junction temperature, taking into account the power dissipation, thermal resistance, and heat sinking provided. Brief non-repetitive excursions of junction temperature above 150°C can be tolerated, provided the duration does not exceed 30 seconds maximum. (Non-repetitive events are defined as not occurring more than once in 24 hours.)
- Pin soldering temperature limit is for 10 seconds maximum duration. Not designed for immersion soldering. Exceeding these limits may cause malfunction or permanent damage to the device.
- Freescaler's Package Reflow capability meets Pb-free requirements for JEDEC standard J-STD-020C. For Peak Package Reflow Temperature and Moisture Sensitivity Levels (MSL), Go to www.freescale.com, search by part number [e.g. remove prefixes/suffixes and enter the core ID to view all orderable parts. (i.e. MC33xxx enter 33xxx), and review parametrics.
- Exposed heatsink pad plus the power and ground pins comprise the main heat conduction paths. The actual $R_{\theta JB}$ (junction-to-PC board) values will vary depending on solder thickness and composition and copper trace thickness and area. Maximum current at maximum die temperature represents ~16 W of conduction loss heating in the diagonal pair of output MOSFETs. Therefore, the $R_{\theta JA}$ must be $< 5.0^\circ\text{C/W}$ for maximum current at 70°C ambient. Module thermal design must be planned accordingly.

STATIC ELECTRICAL CHARACTERISTICS

Table 3. Static Electrical Characteristics

Characteristics noted under conditions $8.0\text{ V} \leq V_{PWR} \leq 28\text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_A = 25^\circ\text{C}$ under nominal conditions, unless otherwise noted. Specifications given for H-Bridge A apply symmetrically to H-Bridge B.

Characteristic	Symbol	Min	Typ	Max	Unit
POWER INPUTS (VPWR)					
Operating Voltage Range ⁽¹⁰⁾					V
Steady-state	$V_{PWR(SS)}$	8.0	–	28	
Transient ($t < 500\text{ ms}$) ⁽¹¹⁾	$V_{PWR(t)}$	–	–	40	
Quasi-Functional ($R_{DS(ON)}$ May Increase by 50%)	$V_{PWR(QF)}$	5.0	–	8.0	
Sleep State Supply Current ⁽¹²⁾	$I_{PWR(SLEEP)}$				μA
$\text{EN}/\overline{\text{D2}} = \text{Logic [0]}, \text{IN1}, \text{IN2}, \text{D1} = \text{Logic [1]}, \text{and } I_{OUT} = 0\text{ A}$		–	–	50	
Standby Supply Current (Part Enabled)	$I_{PWR(STANDBY)}$				mA
$I_{OUT} = 0\text{ A}, V_{EN} = 5.0\text{ V}$		–	–	20	
Under-voltage Lockout Thresholds					
$V_{PWR(\text{falling})}$	$V_{UVLO(ACTIVE)}$	4.15	–	–	V
$V_{PWR(\text{rising})}$	$V_{UVLO(INACTIVE)}$	–	–	5.0	V
Hysteresis	$V_{UVLO(HYS)}$	150	200	350	mV
CHARGE PUMP					
Charge Pump Voltage (CP Capacitor = 33 nF), No PWM	$V_{CP} - V_{PWR}$				V
$V_{PWR} = 5.0\text{ V}$		3.5	–	–	
$V_{PWR} = 28\text{ V}$		–	–	12	
Charge Pump Voltage (CP Capacitor = 33 nF), PWM = 11 kHz	$V_{CP} - V_{PWR}$				V
$V_{PWR} = 5.0\text{ V}$		3.5	–	–	
$V_{PWR} = 28\text{ V}$		–	–	12	
CONTROL INPUTS					
Operating Input Voltage (IN1, IN2, D1, $\text{EN}/\overline{\text{D2}}$, IN3, IN4, D3, $\text{EN}/\overline{\text{D4}}$)	V_I	–	–	5.5	V
Input Voltage (IN1, IN2, D1, $\text{EN}/\overline{\text{D2}}$, IN3, IN4, D3, $\text{EN}/\overline{\text{D4}}$)					
Logic Threshold HIGH	V_{IH}	2.0	–	–	V
Logic Threshold LOW	V_{IL}	–	–	1.0	V
Hysteresis	V_{HYS}	250	400	–	mV
Logic Input Currents, $V_{PWR} = 8.0\text{ V}$	I_{IN}				μA
Input $\text{EN}/\overline{\text{D2}}, \text{EN}/\overline{\text{D4}}$ (internal pull-downs), $V_{IH} = 5.0\text{ V}$		20	80	200	
Inputs IN1, IN2, D1, IN3, IN4, D3 (internal pull-ups), $V_{IL} = 0\text{ V}$		-200	-80	-20	

Notes

- Device specifications are characterized over the range of $8.0\text{ V} \leq V_{PWR} \leq 28\text{ V}$. Continuous operation above 28 V may degrade device reliability. Device is operational down to 5.0V, but below 8.0 V the output resistance may increase by 50 percent.
- Device will survive the transient over-voltage indicated for a maximum duration of 500 ms. Transient not to be repeated more than once every 10 seconds.
- $I_{PWR(SLEEP)}$ is with Sleep Mode activated and $\text{EN}/\overline{\text{D2}} = \text{logic [0]}$, and IN1, IN2, D1 = logic [1] or with these inputs left floating.

Table 3. Static Electrical Characteristics (continued)

Characteristics noted under conditions $8.0\text{ V} \leq V_{PWR} \leq 28\text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_A = 25^\circ\text{C}$ under nominal conditions, unless otherwise noted. Specifications given for H-Bridge A apply symmetrically to H-Bridge B.

Characteristic	Symbol	Min	Typ	Max	Unit
POWER OUTPUTS OUT1, OUT2					
Output-ON Resistance ⁽¹⁴⁾ , $I_{LOAD} = 3.0\text{ A}$ $V_{PWR} = 8.0\text{ V}$, $T_J = 25^\circ\text{C}$ $V_{PWR} = 8.0\text{ V}$, $T_J = 150^\circ\text{C}$ $V_{PWR} = 5.0\text{ V}$, $T_J = 150^\circ\text{C}$	$R_{DS(ON)}$	–	120	–	$\text{m}\Omega$
Output Current Regulation Threshold $T_J < T_{FB}$ $T_J \geq T_{FB}$ (Fold back Region - see Figure 9 and Figure 11) ⁽¹³⁾	I_{LIM}	5.2	6.5	8.0	A
High Side Short Circuit Detection Threshold (Short Circuit to Ground) ⁽¹³⁾	I_{SCH}	11	13	16	A
Low Side Short Circuit Detection Threshold (Short Circuit to V_{PWR}) ⁽¹³⁾	I_{SCL}	9.0	11	14	A
Output Leakage Current ⁽¹⁵⁾ , Outputs off, $V_{PWR} = 28\text{ V}$ $V_{OUT} = V_{PWR}$ $V_{OUT} = \text{Ground}$	$I_{OUTLEAK}$	–	–	100	μA
Output MOSFET Body Diode Forward Voltage Drop, $I_{OUT} = 3.0\text{ A}$	V_F	–	–	2.0	V
Over-temperature Shutdown ⁽¹³⁾ Thermal Limit @ T_J Hysteresis @ T_J	T_{LIM} T_{HYS}	175	–	200	$^\circ\text{C}$
Current Foldback at T_J ⁽¹³⁾	T_{FB}	165	–	185	$^\circ\text{C}$
Current Foldback to Thermal Shutdown Separation ⁽¹³⁾	T_{SEP}	10	–	15	$^\circ\text{C}$

HIGH SIDE CURRENT SENSE FEEDBACK

Feedback Current (pin FB sourcing current) ⁽¹⁶⁾ $I_{OUT} = 0\text{ mA}$ $I_{OUT} = 300\text{ mA}$ $I_{OUT} = 500\text{ mA}$ $I_{OUT} = 1.5\text{ A}$ $I_{OUT} = 3.0\text{ A}$ $I_{OUT} = 6.0\text{ A}$	I_{FB}	0.0	–	50	μA
		0.0	270	750	μA
		0.35	0.775	1.56	mA
		2.86	3.57	4.28	mA
		5.71	7.14	8.57	mA
		11.43	14.29	17.15	mA

STATUS FLAG⁽¹⁷⁾

Status Flag Leakage Current ⁽¹⁸⁾ $V_{SF} = 5.0\text{ V}$	I_{SFLEAK}	–	–	5.0	μA
Status Flag SET Voltage ⁽¹⁹⁾ $I_{SF} = 300\text{ }\mu\text{A}$	V_{SFLOW}	–	–	0.4	V

Notes

- This parameter is Guaranteed By Design.
- Output-ON resistance as measured from output to V_{PWR} and from output to GND.
- Outputs switched OFF via D1 or $\text{EN}/\overline{\text{D2}}$.
- Accuracy is better than 20% from 0.5 A to 6.0 A. Recommended terminating resistor value: $R_{FB} = 270\text{ }\Omega$.
- Status Flag output is an open drain output requiring a pull-up resistor to logic V_{DD} .
- Status Flag Leakage Current is measured with Status Flag HIGH and *not* SET.
- Status Flag Set Voltage measured with Status Flag LOW and SET with $I_{SF} = 300\text{ }\mu\text{A}$. Maximum allowable sink current from this pin is $< 500\text{ }\mu\text{A}$. Maximum allowable pull-up voltage $< 7.0\text{ V}$.

DYNAMIC ELECTRICAL CHARACTERISTICS

Table 4. Dynamic Electrical Characteristics

Characteristics noted under conditions $8.0\text{ V} \leq V_{PWR} \leq 28\text{ V}$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_A = 25^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
TIMING CHARACTERISTICS					
PWM Frequency ⁽²⁰⁾	f_{PWM}	–	–	11	kHz
Maximum Switching Frequency During Current Limit Regulation ⁽²¹⁾	f_{MAX}	–	–	20	kHz
Output ON Delay ⁽²²⁾ $V_{PWR} = 14\text{ V}$	t_{DON}	–	–	18	μs
Output OFF Delay ⁽²²⁾ $V_{PWR} = 14\text{ V}$	t_{DOFF}	–	–	12	μs
I_{LIM} Output Constant-OFF Time ⁽²³⁾	t_A	15	20.5	32	μs
I_{LIM} Blanking Time ⁽²⁴⁾	t_B	12	16.5	27	μs
Disable Delay Time ⁽²⁵⁾	$t_{DDISABLE}$	–	–	8.0	μs
Output Rise and Fall Time ⁽²⁶⁾	t_F, t_R	1.5	3.0	8.0	μs
Short-circuit/Over-temperature Turn-OFF (Latch-OFF) Time ^{(27), (28)}	t_{FAULT}	–	–	8.0	μs
Power-ON Delay Time ⁽²⁸⁾	t_{POD}	–	1.0	5.0	ms
Output MOSFET Body Diode Reverse Recovery Time ⁽²⁸⁾	t_{RR}	75	100	150	ns
Charge Pump Operating Frequency ⁽²⁸⁾	f_{CP}	–	7.0	–	MHz

Notes

20. The maximum PWM frequency should be limited to frequencies < 11 kHz in order to allow the internal high side driver circuitry time to fully enhance the high side MOSFETs.
21. The internal current limit circuitry produces a constant-OFF-time Pulse Width Modulation of the output current. The output load's inductance, capacitance, and resistance characteristics affect the total switching period (OFF-time + ON-time), and thus the PWM frequency during current limit.
22. * Output Delay is the time duration from 1.5V on the IN1 or IN2 input signal to the 20% or 80% point (dependent on the transition direction) of the OUT1 or OUT2 signal. If the output is transitioning HIGH-to-LOW, the delay is from 1.5 V on the input signal to the 80% point of the output response signal. If the output is transitioning LOW-to-HIGH, the delay is from 1.5 V on the input signal to the 20% point of the output response signal. See [Figure 4](#), page 9.
23. The time during which the internal constant-OFF time PWM current regulation circuit has tri-stated the output bridge.
24. The time during which the current regulation threshold is ignored so that the short-circuit detection threshold comparators may have time to act.
25. * Disable Delay Time measurement is defined in [Figure 5](#), page 9.
26. Rise Time is from the 10% to the 90% level and Fall Time is from the 90% to the 10% level of the output signal with $V_{PWR} = 14\text{ V}$, $R_{LOAD} = 3.0\text{ ohm}$. See [Figure 6](#), page 9.
27. Load currents ramping up to the current regulation threshold become limited at the I_{LIM} value (see [Figure 7](#)). The short-circuit currents possess a di/dt that ramps up to the I_{SCH} or I_{SCL} threshold during the I_{LIM} blanking time, registering as a short-circuit event detection and causing the shutdown circuitry to force the output into an immediate tri-state latch-OFF (see [Figure 8](#)). Operation in Current Limit mode may cause junction temperatures to rise. Junction temperatures above $\sim 160^\circ\text{C}$ will cause the output current limit threshold to “fold back”, or decrease, until $\sim 175^\circ\text{C}$ is reached, after which the T_{LIM} thermal latch-OFF will occur. Permissible operation within this fold back region is limited to non-repetitive transient events of duration not to exceed 30 seconds (see [Figure 9](#)).
28. Parameter is Guaranteed By Design.

TIMING DIAGRAMS

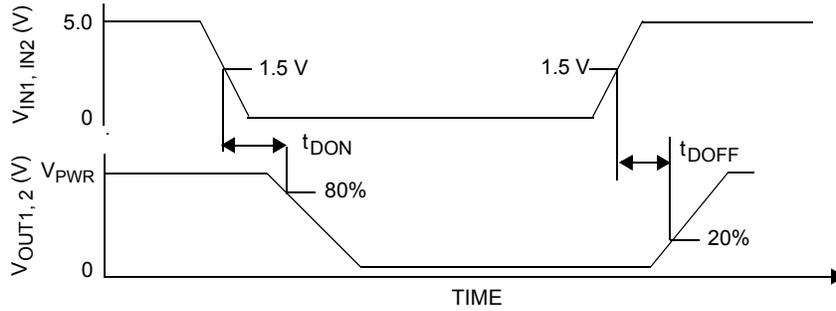


Figure 4. Output Delay Time

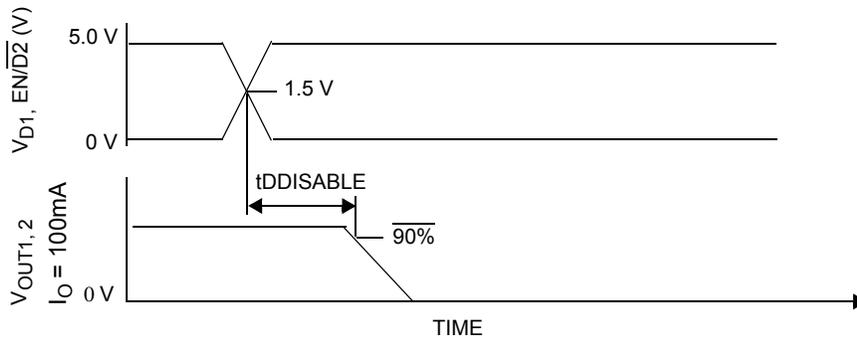


Figure 5. Disable Delay Time

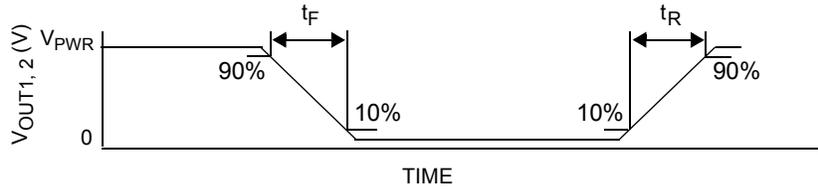


Figure 6. Output Switching Time

Overload Condition

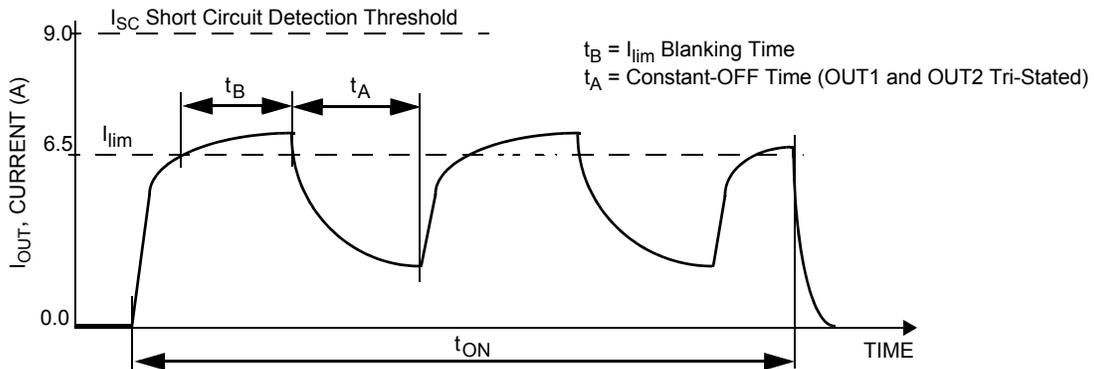


Figure 7. Current Limit Blanking Time and Constant-OFF Time

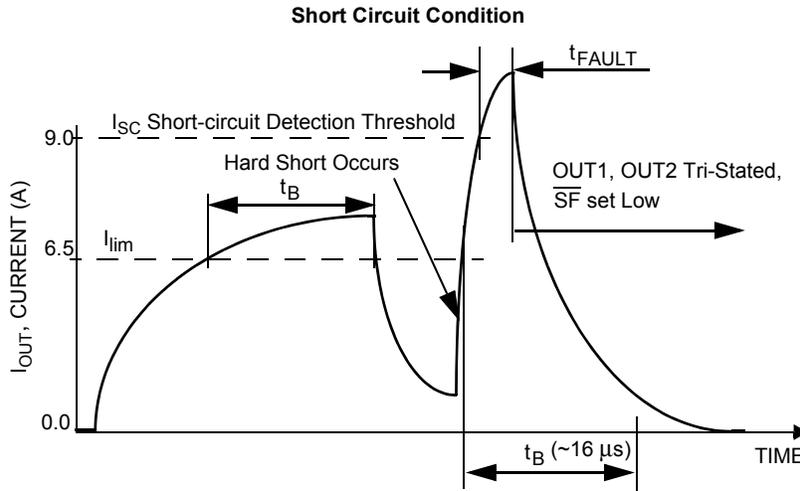


Figure 8. Short-circuit Detection Turn-OFF Time t_{FAULT}

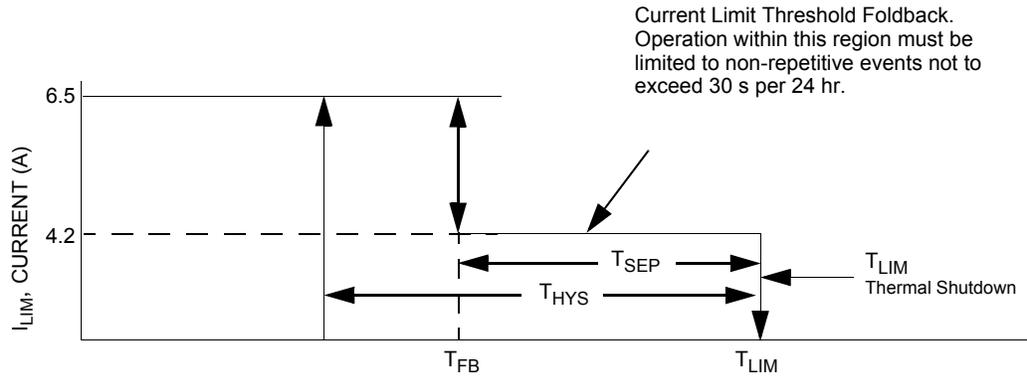


Figure 9. Output Current Limiting Foldback Region

FUNCTIONAL DESCRIPTION

INTRODUCTION

The 33932 has two identical H-Bridge drivers in the same package. The only connection that is shared internally is the Analog Ground (AGND). This description is given for the H-Bridge A half of the total device. However, the H-Bridge B half will exhibit identical behavior.

Numerous protection and operational features (speed, torque, direction, dynamic braking, PWM control, and closed-loop control) make the 33932 a very attractive, cost-effective solution for controlling a broad range of small DC motors. The 33932 outputs are capable of supporting peak DC load currents of up to 5.0 A from a 28 V V_{PWR} source. An internal charge pump and gate drive circuitry are provided that can support external PWM frequencies up to 11 kHz.

The 33932 has an analog feedback (current mirror) output pin (the FB pin) that provides a constant-current source ratioed to the active high side MOSFETs' current. This can be used to provide "real time" monitoring of output current to facilitate closed-loop operation for motor speed/torque control, or for the detection of open load conditions.

Two independent inputs, IN1 and IN2, provide control of the two totem-pole half-bridge outputs. Two independent disable inputs, D1 and $\overline{EN/D2}$, provide the means to force the

H-bridge outputs to a high-impedance state (all H-bridge switches OFF). The $\overline{EN/D2}$ pin also controls an enable function that allows the IC to be placed in a power-conserving Sleep Mode.

The 33932 has output current limiting (via constant OFF-time PWM current regulation), output short-circuit detection with latch-OFF, and over-temperature detection with latch-OFF. Once the device is latched-OFF due to a fault condition, either of the Disable inputs (D1 or $\overline{EN/D2}$), or V_{PWR} must be "toggled" to clear the status flag.

Current limiting (Load Current Regulation) is accomplished by a constant-OFF time PWM method using current limit threshold triggering. The current limiting scheme is unique in that it incorporates a junction temperature-dependent current limit threshold. This means that the current limit threshold is "reduced to around 4.2 A" as the junction temperature increases above 160°C. When the temperature is above 175°C, over-temperature shutdown (latch-OFF) will occur. This combination of features allows the device to continue operating for short periods of time (<30 seconds) with unexpected loads, while still retaining adequate protection for both the device and the load.

FUNCTIONAL PIN DESCRIPTION

POWER GROUND AND ANALOG GROUND (PGND AND AGND)

The power and analog ground pins should be connected together with a very low-impedance connection.

POSITIVE POWER SUPPLY (VPWR)

VPWR pins are the power supply inputs to the device. All VPWR pins must be connected together on the printed circuit board with as short as possible traces, offering as low an impedance as possible between pins.

STATUS FLAG (\overline{SF})

This pin is the device fault status output. This output is an active LOW open drain structure requiring a pull-up resistor to V_{DD} . The maximum V_{DD} is <7.0 V. Refer to [Table 5. Truth Table, page 15 for the SF Output status definition.](#)

INPUT 1,2 AND DISABLE INPUT 1 (IN1, IN2, AND D1)

These pins are input control pins used to control the outputs. These pins are 3.0 V/5.0 V CMOS-compatible inputs with hysteresis. IN1 and IN2 independently control OUT1 and OUT2, respectively. D1 input is used to tri-state disable the H-bridge outputs.

When D1 is SET (D1 = logic HIGH) in the disable state, outputs OUT1 and OUT2 are both tri-state disabled; however, the rest of the device circuitry is fully operational and the supply $I_{PWR(STANDBY)}$ current is reduced to a few mA. Refer to [Table 3. Static Electrical Characteristics, page 6.](#)

H-BRIDGE OUTPUT (OUT1, OUT2)

These pins are the outputs of the H-bridge with integrated free-wheeling diodes. The bridge output is controlled using the IN1, IN2, D1, and $\overline{EN/D2}$ inputs. The outputs have PWM current limiting above the I_{LIM} threshold. The outputs also have thermal shutdown (tri-state latch-OFF) with hysteresis as well as short circuit latch-OFF protection.

A disable timer (time t_b) is incorporated to distinguish between load currents that are higher than the I_{LIM} threshold and short circuit currents. This timer is activated at each output transition.

CHARGE PUMP CAPACITOR (CCP)

This pin is the charge pump output pin and connection for the external charge pump reservoir capacitor. The allowable value is from 30 to 100 nF. This capacitor must be connected from the CCP pin to the VPWR pin. The device cannot operate properly without the external reservoir capacitor.

ENABLE INPUT/DISABLE INPUT 2 (EN/ $\overline{D2}$)

The EN/ $\overline{D2}$ pin performs the same function as D1 pin, when it goes to a logic LOW the outputs are immediately tri-stated. It is also used to place the device in a Sleep Mode so as to consume very low currents. When the EN/ $\overline{D2}$ pin voltage is a logic LOW state, the device is in the Sleep Mode. The device is enabled and fully operational when the EN pin voltage is logic HIGH. An internal pull-down resistor maintains the device in Sleep Mode in the event EN is driven through a high-impedance I/O or an unpowered microcontroller, or the EN/ $\overline{D2}$ input becomes disconnected.

FEEDBACK (FB)

The 33932 has a feedback output (FB) for “real time” monitoring of H-bridge high-side output currents to facilitate closed-loop operation for motor speed and torque control.

The FB pin provides current sensing feedback of the H-bridge high side drivers. When running in the forward or reverse direction, a ground-referenced 0.24% of load current is output to this pin. Through the use of an external resistor to ground, the proportional feedback current can be converted to a proportional voltage equivalent and the controlling microcontroller can “read” the current proportional voltage with its analog-to-digital converter (ADC). This is intended to provide the user with only first-order motor current feedback for motor torque control. The resistance range for the linear operation of the FB pin is $100\ \Omega < R_{FB} < 300\ \Omega$.

If PWM-ing is implemented using the disable pin input (only D1), a small filter capacitor (~1.0 μ F) may be required in parallel with the R_{FB} resistor to ground for spike suppression.

FUNCTIONAL INTERNAL BLOCK DESCRIPTION

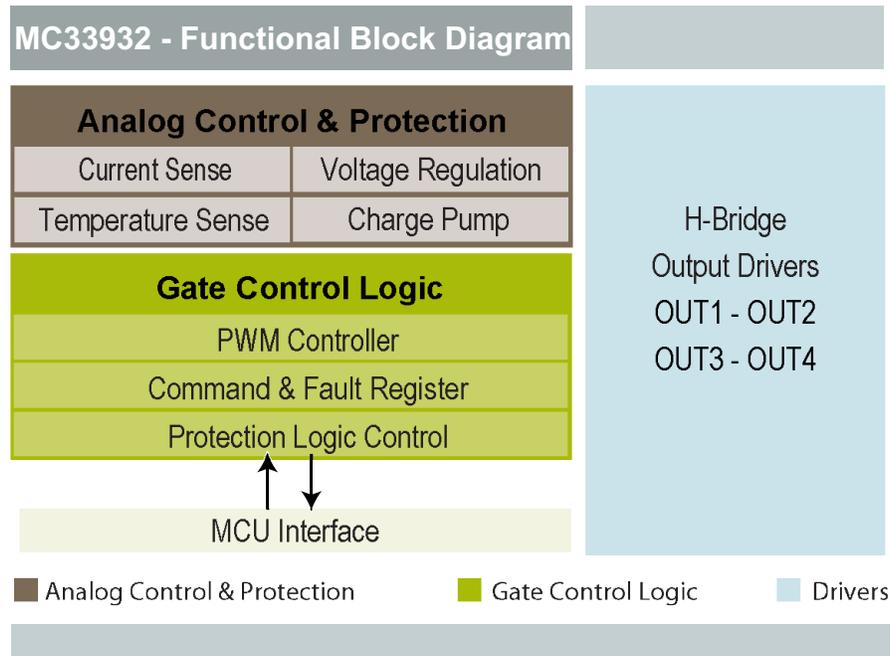


Figure 10. Functional Internal Block Diagram

ANALOG CONTROL AND PROTECTION CIRCUITRY:

An on-chip voltage regulator supplies the internal logic. The charge pump provides gate drive for the H-Bridge MOSFETs. The Current and Temperature sense circuitry provides detection and protection for the output drivers. Output undervoltage protection shuts down the MOSFETS.

GATE CONTROL LOGIC:

The 33932 is a monolithic H-Bridge Power IC designed primarily for any low-voltage DC servo motor control application within the current and voltage limits stated for the device. Two independent inputs provide polarity control of

two half-bridge totem-pole outputs. Two independent disable inputs are provided to force the H-Bridge outputs to tri-state (high impedance off-state).

H-BRIDGE OUTPUT DRIVERS: OUT1 AND OUT2

The H-Bridge is the power output stage. The current flow from OUT1 to OUT2 is reversible and under full control of the user by way of the Input Control Logic. The output stage is designed to produce full load control under all system conditions. All protective and control features are integrated into the Control and Protection blocks. The sensors for current and temperature are integrated directly into the output MOSFET for maximum accuracy and dependability.

FUNCTIONAL DEVICE OPERATION

OPERATIONAL MODES

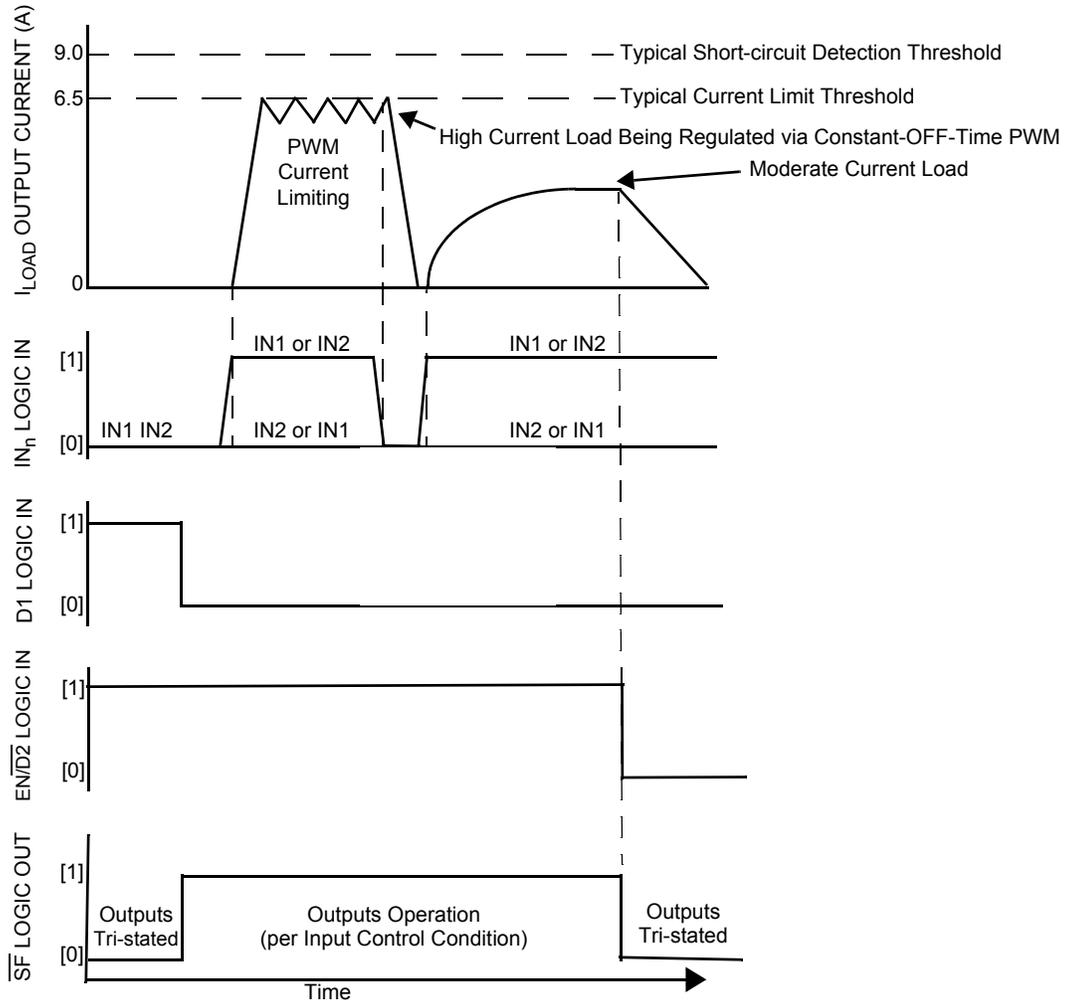


Figure 11. Operating States

LOGIC COMMANDS AND REGISTERS

Table 5. Truth Table

The tri-state conditions and the status flag are reset using D1 or $\overline{D2}$. The truth table uses the following notations: L = LOW, H = HIGH, X = HIGH or LOW, and Z = High-impedance. All output power transistors are switched off.

Device State	Input Conditions				Status \overline{SF}	Outputs	
	$\overline{EN/D2}$	D1	IN1	IN2		OUT1	OUT2
Forward	H	L	H	L	H	H	L
Reverse	H	L	L	H	H	L	H
Free Wheeling Low	H	L	L	L	H	L	L
Free Wheeling High	H	L	H	H	H	H	H
Disable 1 (D1)	H	H	X	X	L	Z	Z
IN1 Disconnected	H	L	Z	X	H	H	X
IN2 Disconnected	H	L	X	Z	H	X	H
D1 Disconnected	H	Z	X	X	L	Z	Z
Under-voltage Lockout ⁽²⁹⁾	H	X	X	X	L	Z	Z
Over-temperature ⁽³⁰⁾	H	X	X	X	L	Z	Z
Short-circuit ⁽³⁰⁾	H	X	X	X	L	Z	Z
Sleep Mode $\overline{EN/D2}$	L	X	X	X	H	Z	Z
$\overline{EN/D2}$ Disconnected	Z	X	X	X	H	Z	Z

Notes

- 29. In the event of an under-voltage condition, the outputs tri-state and status flag is SET logic LOW. Upon under-voltage recovery, status flag is reset automatically or automatically cleared and the outputs are restored to their original operating condition.
- 30. When a short-circuit or over-temperature condition is detected, the power outputs are tri-state latched-OFF independent of the input signals and the status flag is latched to logic LOW. To reset from this condition requires the toggling of either D1, $\overline{EN/D2}$, or V_{PWR} .

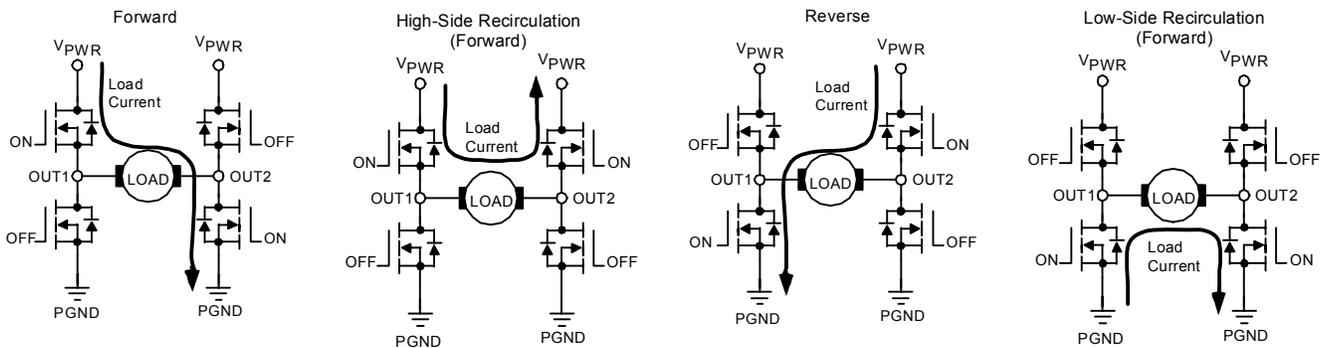


Figure 12. 33932 Power Stage Operation

PROTECTION AND DIAGNOSTIC FEATURES

SHORT-CIRCUIT PROTECTION

If an output short-circuit condition is detected, the power outputs tri-state (latch-OFF) independent of the input (IN1 and IN2) states, and the fault status output flag (SF) is SET to logic LOW. If the D1 input changes from logic HIGH to logic LOW, or if the EN/D2 input changes from logic LOW to logic HIGH, the output bridge will become operational again and the fault status flag will be reset (cleared) to a logic HIGH state.

The output stage will always switch into the mode defined by the input pins (IN1, IN2, D1, and EN/D2), provided the device junction temperature is within the specified operating temperature range.

INTERNAL PWM CURRENT LIMITING

The maximum current flow under normal operating conditions should be less than 5.0 A. The instantaneous load currents will be limited to I_{LIM} via the internal PWM current limiting circuitry. When the I_{LIM} threshold current value is reached, the output stages are tri-stated for a fixed time (T_A) of 20 μ s typical. Depending on the time constant associated with the load characteristics, the output current decreases during the tri-state duration until the next output ON cycle occurs.

The PWM current limit threshold value is dependent on the device junction temperature. When $-40^{\circ}\text{C} < T_J < 160^{\circ}\text{C}$, I_{LIM} is between the specified minimum/maximum values. When T_J exceeds 160°C , the I_{LIM} threshold decreases to 4.2A. Shortly above 175°C the device over-temperature circuit will detect T_{LIM} and an over-temperature shutdown will occur. This feature implements a graceful degradation of operation before thermal shutdown occurs, thus allowing for intermittent unexpected mechanical loads on the motor's gear-reduction train to be handled.

Important Die temperature excursions above 150°C are permitted only for non-repetitive durations < 30 seconds. Provision must be made at the system level to prevent prolonged operation in the current-foldback region.

OVER-TEMPERATURE SHUTDOWN AND HYSTERESIS

If an over-temperature condition occurs, the power outputs are tri-stated (latched-OFF) and the fault status flag (SF) is SET to logic LOW.

To reset from this condition, D1 must change from logic HIGH to logic LOW, or EN/D2 must change from logic LOW to logic HIGH. When reset, the output stage switches ON again, provided that the junction temperature is now below the over-temperature threshold limit minus the hysteresis.

Important Resetting from the fault condition will clear the fault status flag. Powering down and powering up the device will also reset the 33932 from the fault condition.

OUTPUT AVALANCHE PROTECTION

If VPWR were to become an open circuit, the outputs would likely tri-state simultaneously due to the disable logic. This could result in an unclamped inductive discharge. The VPWR input to the 33932 should not exceed 40 V during this transient condition, to prevent electrical overstress of the output drivers. This can be accomplished with a zener clamp or MOV, and/or an appropriately valued input capacitor with sufficiently low ESR (see [Figure 13](#)).

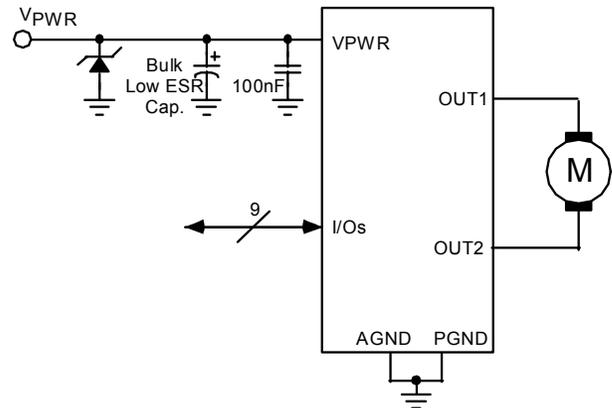


Figure 13. Avalanche Protection

TYPICAL APPLICATIONS

INTRODUCTION

A typical application schematic is shown in [Figure 14](#). For precision high-current applications in harsh, noisy

environments, the V_{PWR} by-pass capacitor may need to be substantially larger.

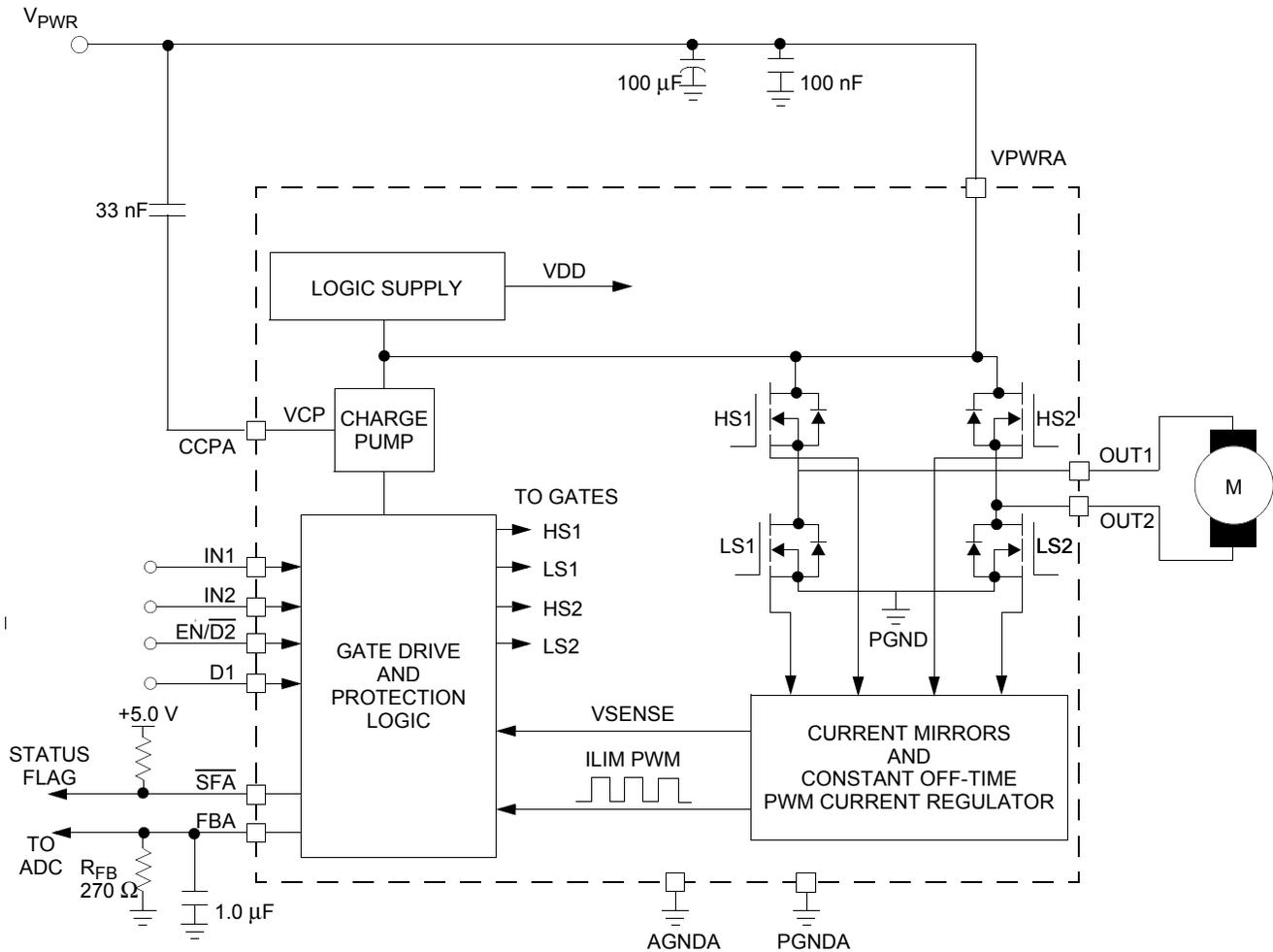
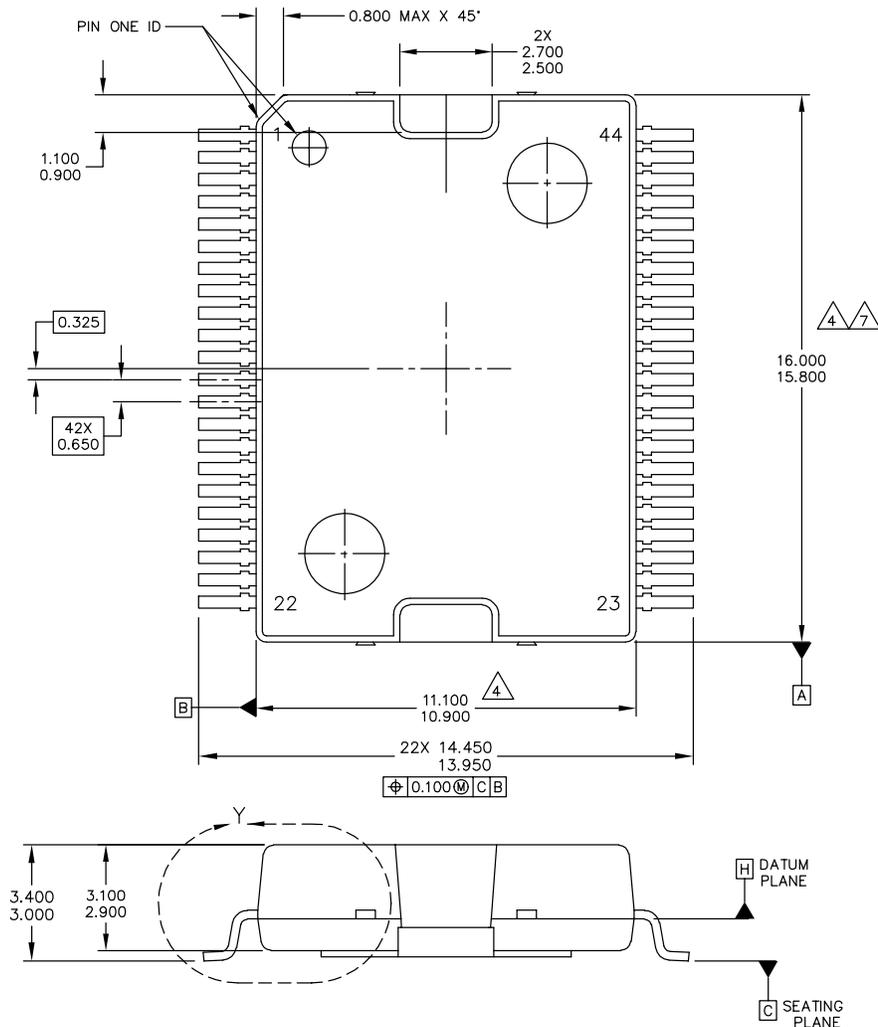


Figure 14. 33932 Typical Application Schematic 1/2 Device

PACKAGING

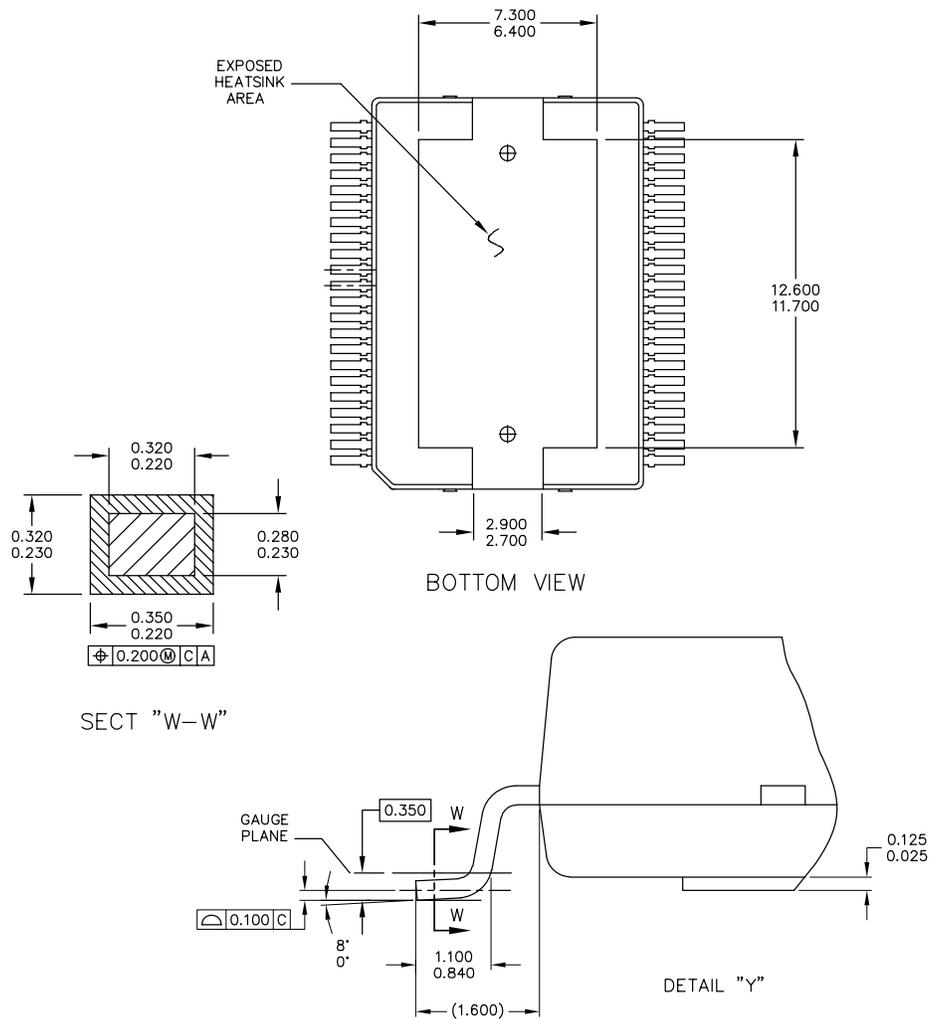
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	CASE NUMBER: 1291-02	16 MAR 2005	
	STANDARD: NON-JEDEC		

VW SUFFIX
44-PIN
98ARH98330A
REVISION B

REVISION HISTORY

REVISION	DATE	DESCRIPTION
1.0	8/2007	<ul style="list-style-type: none">Initial Release
2.0	8/2008	<ul style="list-style-type: none">Added parameters (TBD) for Change Pump Voltages in Table 3.
3.0	11/2008	<ul style="list-style-type: none">Changed maximum $R_{DS(ON)}$ from 225 to 235mΩ.Changed Peak Package Reflow Temperature During Reflow^{(7), (8)}Changed Approximate Junction-to Case Thermal Resistance⁽⁹⁾

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